

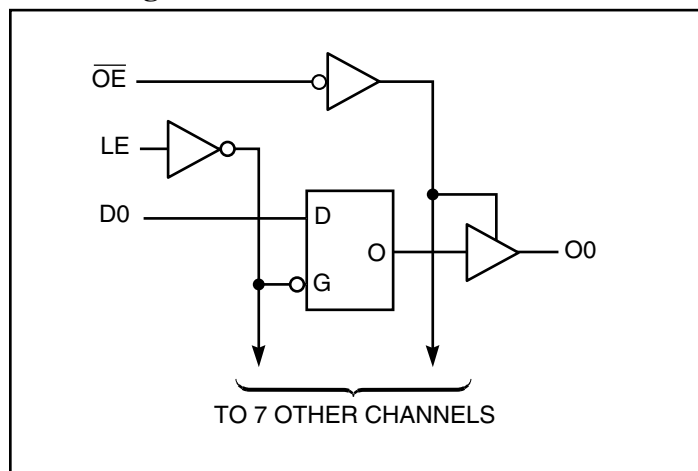
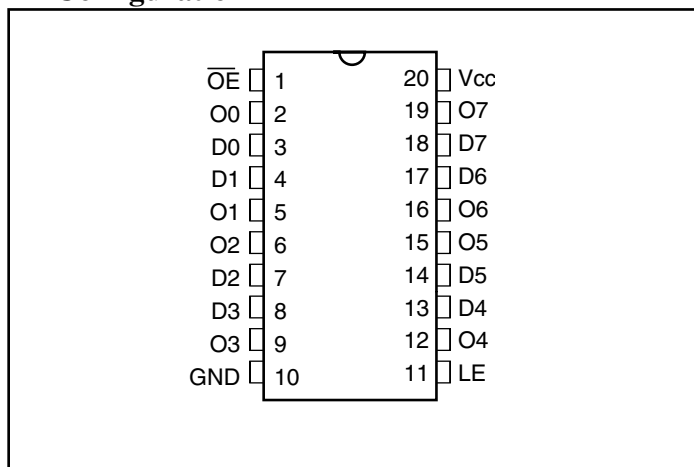
**Fast CMOS 3.3V 8-Bit  
Transparent Latch**
**Features**

- Compatible with LCX™ and LVT™ families of products
- Supports 5V Tolerant Mixed Signal Mode Operation
  - Input can be 3V or 5V
  - Output can be 3V or connected to 5V bus
- Advanced Low Power CMOS Operation
- Excellent output drive capability:  
Balanced drives (24 mA sink and source)
- Low ground bounce outputs
- Hysteresis on all inputs
- Industrial operating temperature range: -40°C to +85°C
- Packaging:
  - 20-pin 173-mil wide plastic TSSOP (L)
  - 20-pin 150-mil wide plastic QSOP (Q)
  - 20-pin 300-mil wide plastic SOIC (S)

**Description**

Pericom Semiconductor's PI74LPT373 is an 8-bit transparent latch designed with 3-state outputs and is intended for bus oriented applications. When Latch Enable (LE) is HIGH, the flip-flops appear transparent to the data. The data that meets the set-up time when LE is LOW is latched. When  $\overline{OE}$  is HIGH, the bus output is in the high impedance state.

The PI74LPT373 can be driven from either 3.3V or 5.0V devices allowing this device to be used as a translator in a mixed 3.3/5.0V system.

**Block Diagram**

**Pin Configuration**

**Truth Table<sup>(1)</sup>**

Inputs			Outputs
D <sub>N</sub>	LE	$\overline{OE}$	O <sub>N</sub>
H	H	L	H
L	H	L	L
X	X	H	Z
X	L	L	O <sub>0</sub>

**Note:**

1. H = High Voltage Level, X = Don't Care,  
L = Low Voltage Level, Z = High Impedance

**Pin Description**

Pin Name	Description
$\overline{OE}$	Output Enable Input (Active LOW)
LE	Latch Enable Input (Active HIGH)
D7-D0	Data Inputs
O7-O0	3-State Outputs
GND	Ground
Vcc	Power

### Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature .....	-55°C to +125°C
Ambient Temperature with Power Applied .....	-40°C to +85°C
Supply Voltage to Ground Potential (Inputs & V <sub>CC</sub> Only).....	-0.5V to +7.0V
Supply Voltage to Ground Potential (Outputs & D/O Only) .....	-0.5V to +7.0V
DC Input Voltage .....	-0.5V to +7.0V
DC Output Current.....	120 mA
Power Dissipation .....	1.0W

**Note:**

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

### DC Electrical Characteristics (Over the Operating Range, T<sub>A</sub> = -40°C to +85°C, V<sub>CC</sub> = 2.7V to 3.6V)

Parameters	Description	Test Conditions <sup>(1)</sup>		Min.	Typ <sup>(2)</sup>	Max.	Units
V <sub>IH</sub>	Input HIGH Voltage (Input pins)	Guaranteed Logic HIGH Level		2.2		5.5	V
	Input HIGH Voltage (I/O pins)			2.0		5.5	
V <sub>IL</sub>	Input LOW Voltage (Input and I/O pins)	Guaranteed Logic LOW Level		-0.5		0.8	
I <sub>IH</sub>	Input HIGH Current (Input pins)	V <sub>CC</sub> = Max.	V <sub>IN</sub> = 5.5V			±1	μA
	Input HIGH Current (I/O pins)	V <sub>CC</sub> = Max.	V <sub>IN</sub> = V <sub>CC</sub>			±1	
I <sub>IL</sub>	Input LOW Current (Input pins)	V <sub>CC</sub> = Max.	V <sub>IN</sub> = GND			±1	
	Input LOW Current (I/O pins)	V <sub>CC</sub> = Max.	V <sub>IN</sub> = GND			±1	
I <sub>OZH</sub>	High Impedance Output Current	V <sub>CC</sub> = Max.	V <sub>OUT</sub> = 5.5V			±1	
I <sub>OZL</sub>	(3-State Output pins)	V <sub>CC</sub> = Max.	V <sub>OUT</sub> = GND			±1	
V <sub>IK</sub>	Clamp Diode Voltage	V <sub>CC</sub> = Min., I <sub>IN</sub> = -18 mA			-0.7	-1.2	V
I <sub>ODL</sub>	Output HIGH Current	V <sub>CC</sub> = 3.3V, V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> , V <sub>O</sub> = 1.5V(3)		-36	-60	-110	mA
I <sub>ODL</sub>	Output LOW Current	V <sub>CC</sub> = 3.3V, V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> , V <sub>O</sub> = 1.5V(3)		50	90	200	
V <sub>OH</sub>	Output HIGH Voltage	V <sub>CC</sub> = Min. V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -0.1 mA	V <sub>CC</sub> -0.2			V
			I <sub>OH</sub> = -3 mA	2.4	3.0		
		V <sub>CC</sub> = 3.0V, V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -8 mA	2.4 <sup>(5)</sup>	3.0		
			I <sub>OH</sub> = -24 mA	2.0			
V <sub>OL</sub>	Output LOW Voltage	V <sub>CC</sub> = Min.	I <sub>OL</sub> = 0.1 mA			0.2	
			V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 16 mA		0.2	0.4
		I <sub>OL</sub> = 24 mA			0.3	0.5	
I <sub>OS</sub>	Short Circuit Current <sup>(4)</sup>	V <sub>CC</sub> = Max. <sup>(3)</sup> , V <sub>OUT</sub> = GND		-60	-85	-240	mA
I <sub>OFF</sub>	Power Down Disable	V <sub>CC</sub> = 0V, V <sub>IN</sub> or V <sub>OUT</sub> ≤ 4.5V				±100	μA
V <sub>H</sub>	Input Hysteresis				150		mV

**Notes:**

- For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- Typical values are at V<sub>CC</sub> = 3.3V, +25°C ambient and maximum loading.
- Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
- This parameter is guaranteed but not tested.
- V<sub>OH</sub> = V<sub>CC</sub> - 0.6V at rated current.

**Capacitance** ( $T_A = 25^\circ\text{C}$ ,  $f = 1\text{ MHz}$ )

Parameters <sup>(1)</sup>	Description	Test Conditions	Typ	Max.	Units
$C_{IN}$	Input Capacitance	$V_{IN} = 0V$	4.5	6	pF
$C_{OUT}$	Output Capacitance	$V_{OUT} = 0V$	5.5	8	

**Note:**

- This parameter is determined by device characterization but is not production tested.

**Power Supply Characteristics**

Parameters	Description	Test Conditions <sup>(1)</sup>		Min.	Typ <sup>(2)</sup>	Max.	Units
$I_{CC}$	Quiescent Power Supply Current	$V_{CC} = \text{Max.}$	$V_{IN} = \text{GND or } V_{CC}$		0.1	10	$\mu\text{A}$
$\Delta I_{CC}$	Quiescent Power Supply Current TTL Inputs HIGH	$V_{CC} = \text{Max.}$	$V_{IN} = V_{CC} - 0.6V^{(3)}$			500	
$I_{CCD}$	Dynamic Power Supply <sup>(4)</sup>	$V_{CC} = \text{Max.},$ Outputs Open $\overline{OE} = \text{GND}$ One Bit Toggling 50% Duty Cycle	$V_{IN} = V_{CC}$ $V_{IN} = \text{GND}$		50	75	$\mu\text{A}/\text{MHz}$
$I_C$	Total Power Supply Current <sup>(6)</sup>	$V_{CC} = \text{Max.},$ Outputs Open $f_i = 10\text{ MHz}$ 50% Duty Cycle $\overline{OE} = \text{GND}$ One Bit Toggling	$V_{IN} = V_{CC} - 0.6V$ $V_{IN} = \text{GND}$		0.6	2.3	mA
		$V_{CC} = \text{Max.},$ Outputs Open $f_i = 2.5\text{ MHz}$ 50% Duty Cycle $\overline{OE} = \text{GND}$ 8 Bits Toggling	$V_{IN} = V_{CC} - 0.6V$ $V_{IN} = \text{GND}$		2.1	4.7 <sup>(5)</sup>	

**Notes:**

- For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device.
- Typical values are at  $V_{CC} = 3.3V$ ,  $+25^\circ\text{C}$  ambient.
- Per TTL driven input; all other inputs at  $V_{CC}$  or GND.
- This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
- Values for these conditions are examples of the  $I_{CC}$  formula. These limits are guaranteed but not tested.
- $I_C = I_{\text{QUIESCENT}} + I_{\text{INPUTS}} + I_{\text{DYNAMIC}}$   
 $I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP}/2 + f_i N_i)$   
 $I_{CC} = \text{Quiescent Current } (I_{CCL}, I_{CCH} \text{ and } I_{CCZ})$   
 $\Delta I_{CC} = \text{Power Supply Current for a TTL High Input}$   
 $D_H = \text{Duty Cycle for TTL Inputs High}$   
 $N_T = \text{Number of TTL Inputs at } D_H$   
 $I_{CCD} = \text{Dynamic Current Caused by an Input Transition Pair (HLH or LHL)}$   
 $f_{CP} = \text{Clock Frequency for Register Devices (Zero for Non-Register Devices)}$   
 $N_{CP} = \text{Number of Clock Inputs at } f_{CP}$   
 $f_i = \text{Input Frequency}$   
 $N_i = \text{Number of Inputs at } f_i$   
 All currents are in milliamps and all frequencies are in megahertz.

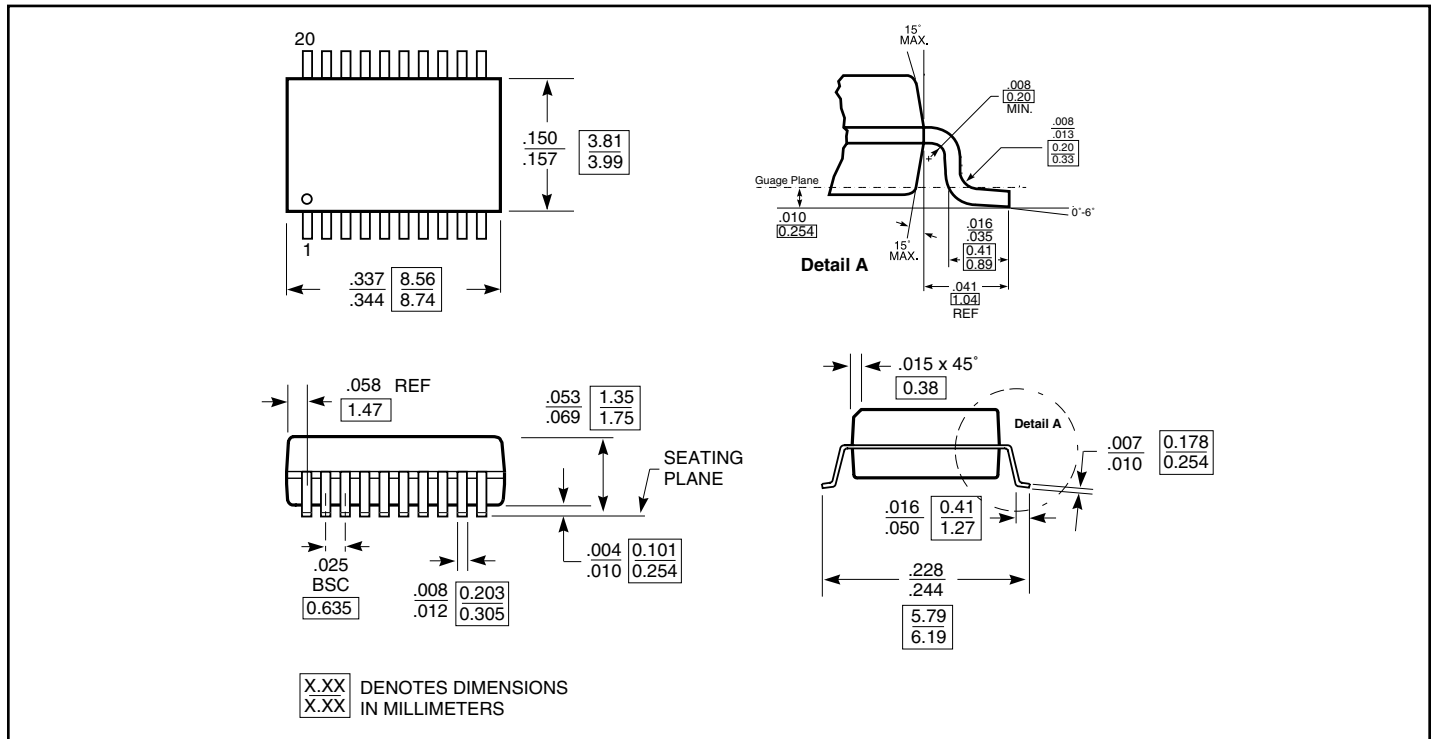
**Switching Characteristics over Operating Range<sup>(1)</sup>**

Parameters	Description	Conditions <sup>(2)</sup>	LPT373		LPT373A		LPT373C		Unit
			Com.		Com.		Com.		
			Min <sup>(3)</sup>	Max	Min <sup>(3)</sup>	Max	Min <sup>(3)</sup>	Max	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Dx to Ox	C <sub>L</sub> = 50pF R <sub>L</sub> = 500 Ω	1.5	8.0	1.5	5.2	1.5	4.2	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay LE to Ox		2.0	8.5	2.0	8.5	2.0	5.5	
t <sub>PZH</sub> t <sub>PZL</sub>	Output Enable Time $\overline{OE}$ to Ox		1.5	8.5	1.5	6.5	1.5	5.5	
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output Disable Time <sup>(4)</sup> $\overline{OE}$ to Ox		1.5	7.5	1.5	5.5	1.5	5.0	
t <sub>SU</sub>	Setup Time HIGH or LOW, Dx to LE		2.0		2.0		2.0		
t <sub>H</sub>	Hold Time HIGH or LOW, Dx to LE		1.5		1.5		1.5		
t <sub>W</sub>	LE Pulse Width HIGH <sup>(4)</sup>		6.0		5.0		5.0		
t <sub>SK(o)</sub>	Output Skew <sup>(5)</sup>			0.5		0.5		0.5	

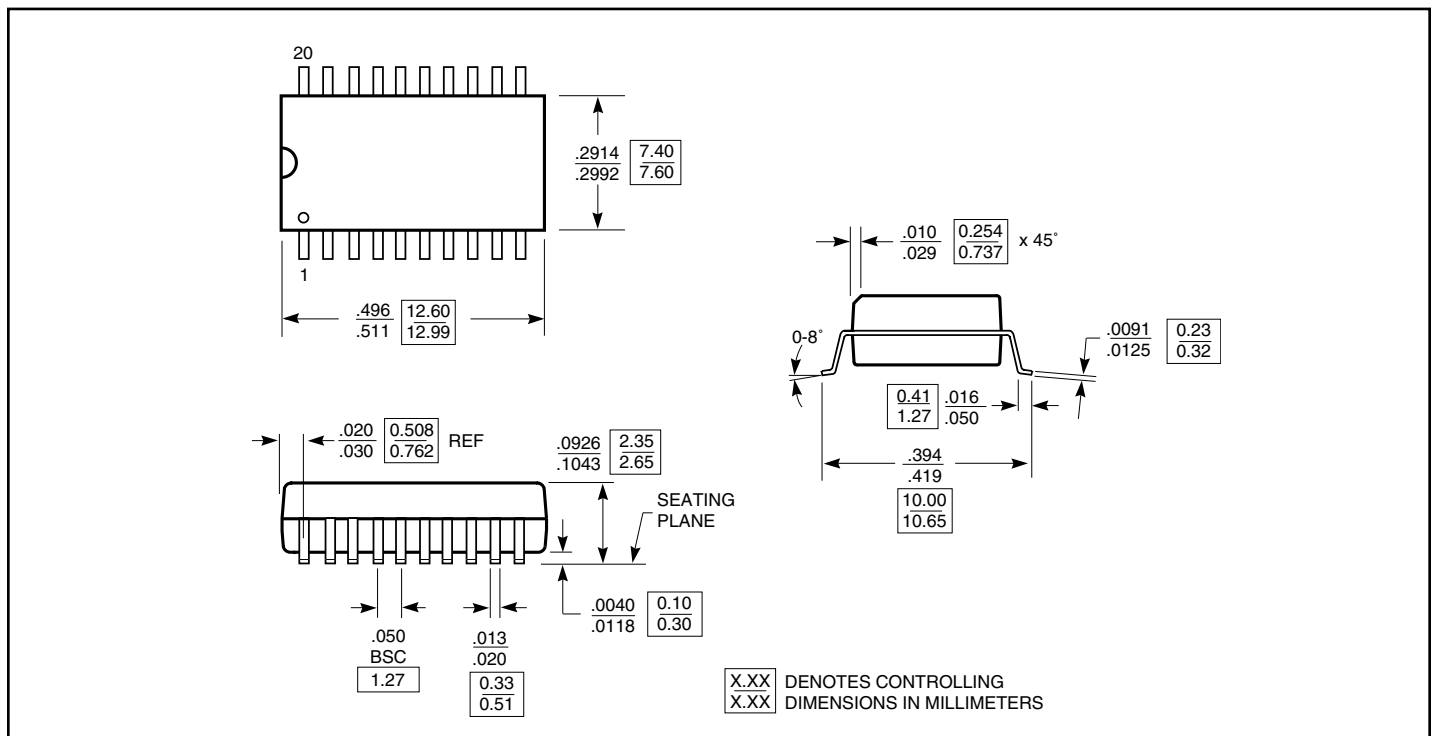
**Notes:**

1. Propagation Delays and Enable/Disable times are with V<sub>CC</sub> = 3.3V ±0.3V, normal range. For V<sub>CC</sub> = 2.7V, extended range, all Propagation Delays and Enable/Disable times should be degraded by 20%.
2. See test circuit and wave forms.
3. Minimum limits are guaranteed but not tested on Propagation Delays.
4. This parameter is guaranteed but not production tested.
5. Skew between any two outputs, of the same package, switching in the same direction. This parameter is guaranteed by design.

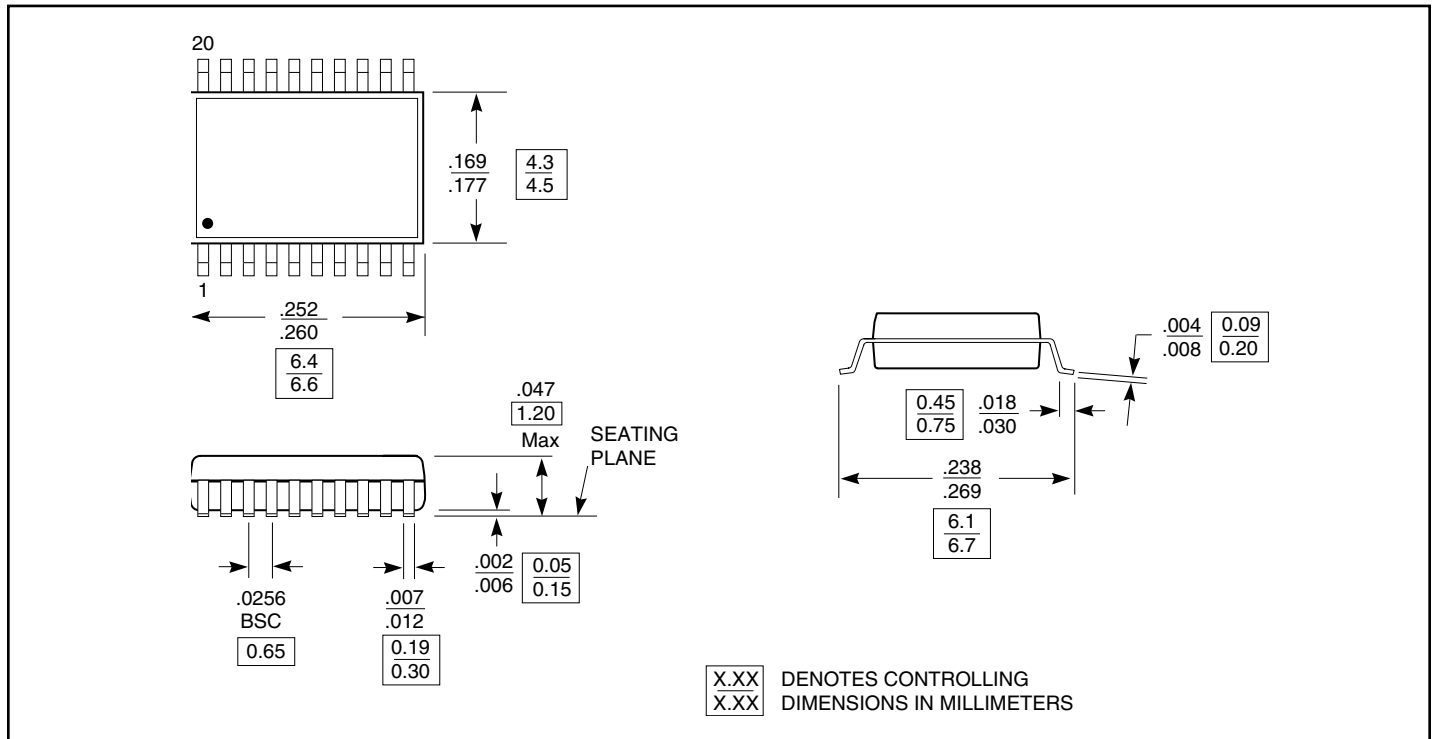
Packaging Mechanical: 20-pin QSOP (Q)



Packaging Mechanical: 20-pin SOIC (S)



**Packaging Mechanical: 20-pin TSSOP (L)**



**Ordering Information**

Ordering Code	Package Code	Speed Grade	Description
PI74LPT373Q	Q	Blank	20-pin 150-mil wide plastic QSOP
PI74LPT373L	L	Blank	20-pin 173-mil wide plastic TSSOP
PI74LPT373AQ	Q	A	20-pin 150-mil wide plastic QSOP
PI74LPT373AS	S	A	20-pin 300-mil wide plastic SOIC
PI74LPT373CQ	Q	C	20-pin 150-mil wide plastic QSOP
PI74LPT373CS	S	C	20-pin 300-mil wide plastic SOIC
PI74LPT373CL	L	C	20-pin 173-mil wide plastic TSSOP

**Notes:**

1. Thermal characteristics can be found on the company web site at [www.pericom.com/packaging/](http://www.pericom.com/packaging/)